

PZUxB series

Single Zener diodes in a SOD323F package

Rev. 02 — 15 November 2009 Product data sheet

1. Product profile

1.1 General description

General-purpose Zener diodes in a SOD323F (SC-90) very small and flat lead Surface Mounted Device (SMD) plastic package.

1.2 Features

- Total power dissipation: ≤ 310 mW
- Tolerance series: B: approximately ±5 %; B1, B2, B3: sequential, approximately ±2 %
- Small plastic package suitable for surface mounted design
- Wide working voltage range: nominal 2.4 V to 36 V

1.3 Applications

- General regulation functions

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
V_F	forward voltage	I_F = 100 mA	[1]	-	-	1.1	V
P_{tot}	total power dissipation	$T_{amb} \leq 25$ °C	[2]	-	-	310	mW
			[3]	-	-	550	mW

[1] Pulse test: $t_p \leq 300$ μs; $\delta \leq 0.02$

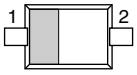
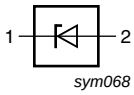
[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1cm^2.

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2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Symbol
1	cathode [1]		 sym068
2	anode		

[1] The marking bar indicates the cathode

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PZU2.4B to PZU36B[1]	SC-90	plastic surface mounted package; 2 leads	SOD323F

[1] The series consists of 97 types with nominal working voltages from 2.4 V to 36 V.

4. Marking

Table 4. Marking codes

Type number	Marking code				Type number	Marking code			
	B	B1	B2	B3		B	B1	B2	B3
PZU2.4	G3	-	-	-	PZU10	GJ	FH	HF	KB
PZU2.7	G4	F3	H1	-	PZU11	GK	FJ	HG	KC
PZU3.0	G5	F4	H2	-	PZU12	GL	FK	HH	KD
PZU3.3	G6	F5	H3	-	PZU13	GM	FL	HJ	KE
PZU3.6	G7	F6	H4	-	PZU14	-	-	HK	-
PZU3.9	G8	F7	H5	-	PZU15	GN	FM	HL	KF
PZU4.3	G9	F8	H6	HS	PZU16	GP	FN	HM	KG
PZU4.7	GA	F9	H7	HT	PZU18	GQ	FP	HN	KH
PZU5.1	GB	FA	H8	HU	PZU20	GR	FQ	HP	KJ
PZU5.6	GC	FB	H9	HV	PZU22	GS	FR	HQ	KK
PZU6.2	GD	FC	HA	HW	PZU24	GT	FS	HR	KL
PZU6.8	GE	FD	HB	HX	PZU27	GU	-	-	-
PZU7.5	GF	FE	HC	HY	PZU30	GV	-	-	-
PZU8.2	GG	FF	HD	HZ	PZU33	GW	-	-	-
PZU9.1	GH	FG	HE	KA	PZU36	GX	-	-	-

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5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
I_F	forward current			-	200	mA
I_{ZSM}	non-repetitive peak reverse current			-	see Table 8 and 9	
P_{ZSM}	non-repetitive peak reverse power dissipation		[1]	-	40	W
P_{tot}	total power dissipation	$T_{amb} \leq 25$ °C	[2]	-	310	mW
			[3]	-	550	mW
T_j	junction temperature			-	150	°C
T_{amb}	ambient temperature			−65	+150	°C
T_{stg}	storage temperature			−65	+150	°C

[1] t_p = 100 μs; square wave; T_j = 25 °C prior to surge

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1cm^2.

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	400	K/W
			[2]	-	-	230	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		[3]	-	-	55	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1cm^2.

[3] Soldering point of cathode tab

7. Characteristics

Table 7. Characteristics

T_j = 25 °C unless otherwise specified

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
V_F	forward voltage	I_F = 10 mA	[1]	-	-	0.9	V
		I_F = 100 mA	[1]	-	-	1.1	V

[1] Pulse test: $t_p \leq 300$ μs; $\delta \leq 0.02$

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Table 8. Characteristics per type; PZU2.4B to PZU5.6B3

T_j = 25 °C unless otherwise specified

PZU xxx	Sel	Working voltage V_Z (V); I_Z = 5 mA		Maximum differential resistance r_{dif} (Ω)		Reverse current I_R (μA)		Temperature coefficient S_Z (mV/K); I_Z = 5 mA	Diode capacitance C_d (pF)[1]	Non-repetitive peak reverse current I_{ZSM} (A)[2]
		Min	Max	I_Z = 0.5 mA	I_Z = 5 mA	Max	V_R (V)	Typ	Max	Max
2.4	B	2.3	2.6	1000	100	50	1	−1.6	450	8
2.7	B	2.5	2.9	1000	100	20	1	−2.0	440	8
	B1	2.5	2.75							
	B2	2.65	2.9							
3.0	B	2.80	3.20	1000	95	10	1	−2.1	425	8
	B1	2.80	3.05							
	B2	2.95	3.20							
3.3	B	3.10	3.50	1000	95	5	1	−2.4	410	8
	B1	3.10	3.35							
	B2	3.25	3.50							
3.6	B	3.40	3.80	1000	90	5	1	−2.4	390	8
	B1	3.40	3.65							
	B2	3.55	3.80							
3.9	B	3.70	4.10	1000	90	3	1	−2.5	370	8
	B1	3.70	3.97							
	B2	3.87	4.10							
4.3	B	4.01	4.48	1000	90	3	1	−2.5	350	8
	B1	4.01	4.21							
	B2	4.15	4.34							
	B3	4.28	4.48							
4.7	B	4.42	4.90	800	80	2	1	−1.4	325	8
	B1	4.42	4.61							
	B2	4.55	4.75							
	B3	4.69	4.90							
5.1	B	4.84	5.37	250	60	2	1.5	0.3	300	5.5
	B1	4.84	5.04							
	B2	4.98	5.20							
	B3	5.14	5.37							
5.6	B	5.31	5.92	100	40	1	2.5	1.9	275	5.5
	B1	5.31	5.55							
	B2	5.49	5.73							
	B3	5.67	5.92							

[1] f = 1 MHz; V_R = 0 V

[2] t_p = 100 μs; square wave; T_j = 25 °C prior to surge

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Table 9. Characteristics per type; PZU6.2B to PZU36B

T_j = 25 °C unless otherwise specified

PZU xxx	Sel	Working voltage V_Z (V); I_Z = 5 mA		Maximum differential resistance r_{dif} (Ω)		Reverse current I_R (nA)		Temperature coefficient S_Z (mV/K); I_Z = 5 mA	Diode capacitance C_d (pF)[1]	Non-repetitive peak reverse current I_{ZSM} (A)[2]
		Min	Max	I_Z = 0.5 mA	I_Z = 5 mA	Max	V_R (V)	Typ	Max	Max
6.2	B	5.86	6.53	80	30	500	3	2.7	250	5.5
	B1	5.86	6.12							
	B2	6.06	6.33							
	B3	6.26	6.53							
6.8	B	6.47	7.14	60	20	500	3.5	3.4	215	5.5
	B1	6.47	6.73							
	B2	6.65	6.93							
	B3	6.86	7.14							
7.5	B	7.06	7.84	60	10	500	4	4.0	170	3.5
	B1	7.06	7.36							
	B2	7.28	7.60							
	B3	7.52	7.84							
8.2	B	7.76	8.64	60	10	500	5	4.6	150	3.5
	B1	7.76	8.10							
	B2	8.02	8.36							
	B3	8.28	8.64							
9.1	B	8.56	9.55	60	10	500	6	5.5	120	3.5
	B1	8.56	8.93							
	B2	8.85	9.23							
	B3	9.15	9.55							
10	B	9.45	10.55	60	10	100	7	6.4	110	3.5
	B1	9.45	9.87							
	B2	9.77	10.21							
	B3	10.11	10.55							
11	B	10.44	11.56	60	10	100	8	7.4	108	3
	B1	10.44	10.88							
	B2	10.76	11.22							
	B3	11.10	11.56							
12	B	11.42	12.60	80	10	100	9	8.4	105	3
	B1	11.42	11.90							
	B2	11.74	12.24							
	B3	12.08	12.60							
13	B	12.47	13.96	80	10	100	10	9.4	103	2.5
	B1	12.47	13.03							
	B2	12.91	13.49							
	B3	13.37	13.96							
14	B2	13.70	14.30	80	10	100	11	10.4	101	2

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Table 9. Characteristics per type; PZU6.2B to PZU36B *…continued*

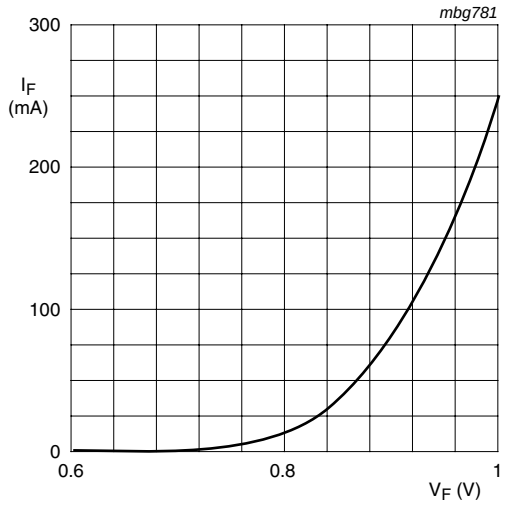
T_j = 25 °C unless otherwise specified

PZU xxx	Sel	Working voltage V_Z (V); I_Z = 5 mA		Maximum differential resistance r_{dif} (Ω)		Reverse current I_R (nA)		Temperature coefficient S_Z (mV/K); I_Z = 5 mA	Diode capacitance C_d (pF)[1]	Non-repetitive peak reverse current I_{ZSM} (A)[2]
		Min	Max	I_Z = 0.5 mA	I_Z = 5 mA	Max	V_R (V)	Typ	Max	Max
15	B	13.84	15.52	80	15	50	11	11.4	99	2
	B1	13.84	14.46							
	B2	14.34	14.98							
	B3	14.85	15.52							
16	B	15.37	17.09	80	20	50	12	12.4	97	1.5
	B1	15.37	16.01							
	B2	15.85	16.51							
	B3	16.35	17.09							
18	B	16.94	19.03	80	20	50	13	14.4	93	1.5
	B1	16.94	17.70							
	B2	17.56	18.35							
	B3	18.21	19.03							
20	B	18.86	21.08	100	20	50	15	16.4	88	1.5
	B1	18.86	19.70							
	B2	19.52	20.39							
	B3	20.21	21.08							
22	B	20.88	23.17	100	25	50	17	18.4	84	1.3
	B1	20.88	21.77							
	B2	21.54	22.47							
	B3	22.23	23.17							
24	B	22.93	25.57	120	30	50	19	20.4	80	1.3
	B1	22.93	23.96							
	B2	23.72	24.78							
	B3	24.54	25.57							
27	B	25.1	28.9	150	40	50	21	23.4	73	1
30	B	28	32	200	40	50	23	26.6	66	1
33	B	31	35	250	40	50	25	29.7	60	0.9
36	B	34	38	300	60	50	27	33.0	59	0.8

[1] f = 1 MHz; V_R = 0 V

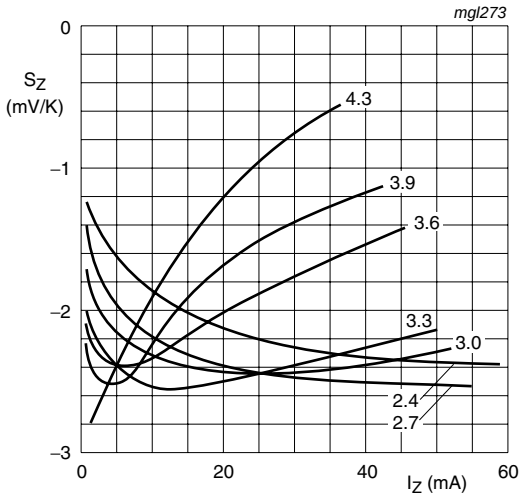
[2] t_p = 100 µs; square wave; T_j = 25 °C prior to surge

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T_j = 25 °C

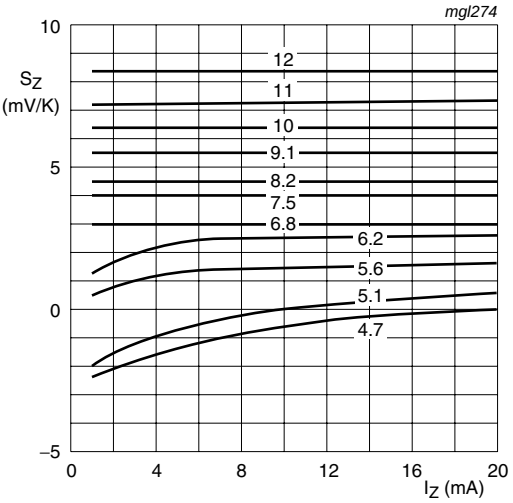
Fig 1. Forward current as a function of forward voltage; typical values



PZU2.4B to PZU4.3B

T_j = 25 °C to 150 °C

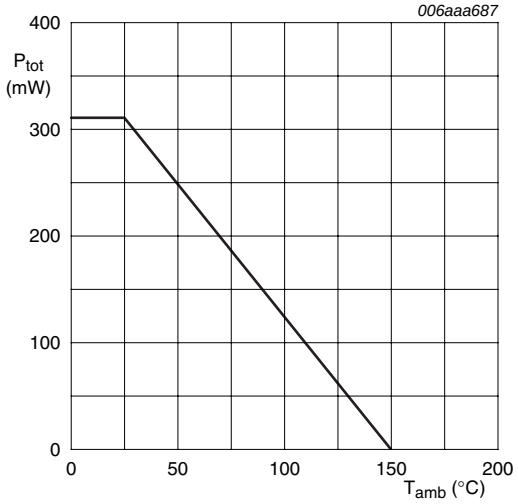
Fig 2. Temperature coefficient as a function of working current; typical values



PZU4.7B to PZU12B

T_j = 25 °C to 150 °C

Fig 3. Temperature coefficient as a function of working current; typical values



FR4 PCB, standard footprint

Fig 4. Power derating curve

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8. Package outline

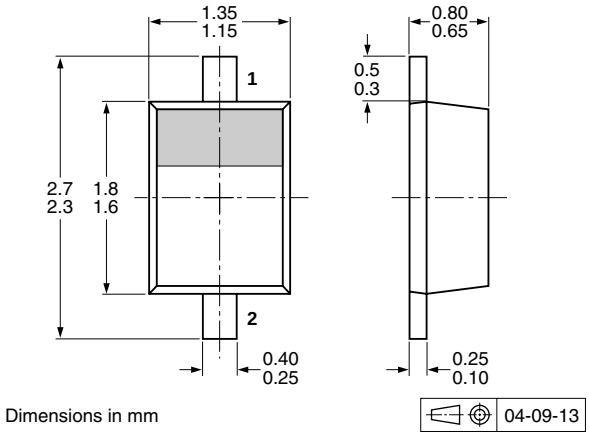


Fig 5. Package outline SOD323F (SC-90)

9. Packing information

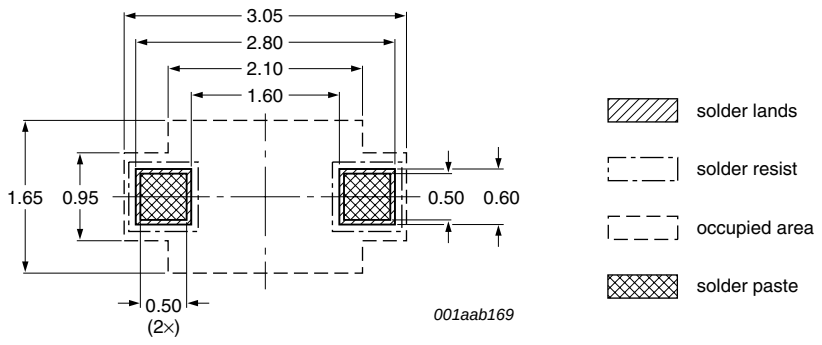
Table 10. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity	
			3000	10000
PZU2.4B to PZU36B	SOD323F	4 mm pitch, 8 mm tape and reel	-115	-135

[1] For further information and the availability of packing methods, see Section 14.

10. Soldering



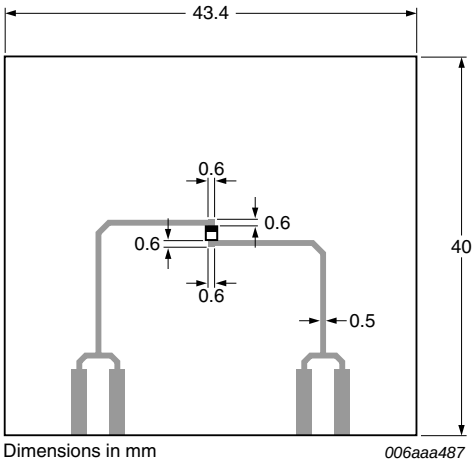
Reflow soldering is the only recommended soldering method.

Dimensions in mm

Fig 6. Reflow soldering footprint SOD323F (SC-90)

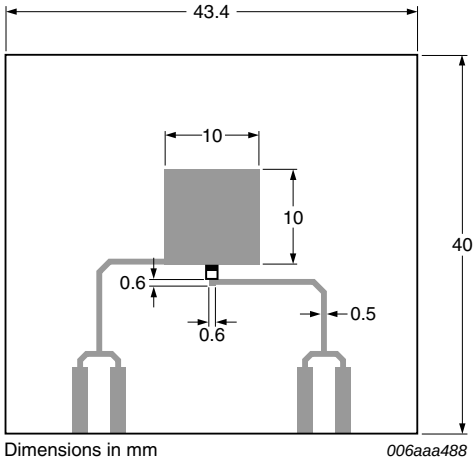
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11. Mounting



PCB thickness = 1.6 mm

Fig 7. FR4 PCB, standard footprint



PCB thickness = 1.6 mm

Fig 8. FR4 PCB, mounting pad for cathode 1cm^2

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12. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PZUXB_SER_2	20091115	Product data sheet	-	PZUXB_SER_1
Modifications:	• This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content.			
PZUXB_SER_1	20060307	Product data sheet	-	-

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13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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